NSN 5961-01-104-5810

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-104-5810 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.335 inches **Function For Which Designed:** Photodiode **Mounting Method: Terminal Terminal Circle Diameter:** 0.210 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 350.0 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 5.00 microamperes repetitive peak forward current peak **Capacitance Rating In Picofarads:** 4.0 **Maximum Operating Tempurature Per Measurement Point:** 60.0 degrees celsius ambient air **Test Data Document:** 82577-13043759 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**